L Number	Hits	Search Text	DB	Time stamp
-	2	"20040125656"	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/06 19:02
-	34	Mizoguchi-Shinichi.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/03 12:53
-	54	Futatsuya-Tomoshi.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/03 12:54
-	61	Hayasaka-Takashi.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/03 12:55
-	1	Mizoguchi-Shinichi.in. and Futatsuya-Tomoshi.in. and Hayasaka-Takashi.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/03 12:55
-	2	Mizoguchi-Shinichi.in. and (erasing near4 data) and (nonvolatile adj semiconductor)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/03 12:56
-	13	Futatsuya-Tomoshi.in. and (erasing near4 data) and (nonvolatile adj semiconductor)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/03 12:56
-	1	Hayasaka-Takashi.in. and (erasing near4 data) and (nonvolatile adj semiconductor)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/03 12:57
-	1	Hayasaka-Takashi.in. and (nonvolatile adj semiconductor)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/03 12:57
-	2	Mizoguchi-Shinichi.in. and (nonvolatile adj semiconductor)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/03 12:57
-	25	Futatsuya-Tomoshi.in. and (nonvolatile adj semiconductor)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/03 12:57
-	38893	nonvolatile adj3 memory	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/06 19:03
-	754	(nonvolatile adj3 memory) and method adj2 eras$6	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/06 19:04
-	14	((nonvolatile adj3 memory) and method adj2 eras$6) and overeras$6 adj2 state	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/06 19:04
-	2	((nonvolatile adj3 memory) and method adj2 eras$6) and recovery adj2 state	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/06 19:05
-	303	((nonvolatile adj3 memory) and method adj2 eras$6) and pulse	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/06 19:05

-	246	(((nonvolatile adj3 memory) and method adj2 eras$6) and pulse) and block	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/06 19:06
-	70	((((nonvolatile adj3 memory) and method adj2 eras$6) and pulse) and block) and potential adj5 word adj line	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/06 19:07
-	8	((nonvolatile adj3 memory) and method adj2 eras$6) and first adj2 eras$6 adj2 state	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/06 19:10
-	6	((nonvolatile adj3 memory) and method adj2 eras$6) and second adj2 eras$6 adj2 state	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/06 19:08
-	6	(((nonvolatile adj3 memory) and method adj2 eras$6) and first adj2 eras$6 adj2 state) and first adj2 eras$6 adj2 pulse	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/06 19:11
-	5	(((nonvolatile adj3 memory) and method adj2 eras$6) and first adj2 eras$6 adj2 state) and second adj2 eras$6 adj2 pulse	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/06 19:13
-	5	((((nonvolatile adj3 memory) and method adj2 eras$6) and first adj2 eras$6 adj2 state) and first adj2 eras$6 adj2 pulse) and ((((nonvolatile adj3 memory) and method adj2 eras$6) and first adj2 eras$6 adj2 state) and second adj2 eras$6 adj2 pulse)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/06 19:13
-	5	(((((nonvolatile adj3 memory) and method adj2 eras$6) and first adj2 eras$6 adj2 state) and first adj2 eras$6 adj2 pulse) and ((((nonvolatile adj3 memory) and method adj2 eras$6) and first adj2 eras$6 adj2 state) and second adj2 eras$6 adj2 pulse)) and erase adj verify	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/06 19:23
-	7	"6330192"	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/09/06 19:23